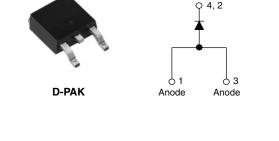
Vishay High Power Products

Schottky Rectifier, 3.5 A



Base

cathode

PRODUCT SUMMARY		
I _{F(AV)}	3.5 A	
V _R	60 V	

FEATURES

- Popular D-PAK outline
- · Small foot print, surface mountable
- · Low forward voltage drop
- High frequency operation
- · Guard ring for enhanced ruggedness and long term reliability
- Lead (Pb)-free ("PbF" suffix)
- · Designed and qualified for AEC Q101 level

DESCRIPTION

The 30WQ06FNPbF surface mount Schottky rectifier has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS				
SYMBOL	CHARACTERISTICS	VALUES	UNITS	
I _{F(AV)}	Rectangular waveform	3.5	A	
V _{RRM}		60	V	
I _{FSM}	t _p = 5 μs sine	490	A	
V _F	3 Apk, T _J = 125 °C	0.53	V	
TJ		- 40 to 150	°C	

VOLTAGE RATINGS				
PARAMETER	SYMBOL	30WQ06FNPbF	UNITS	
Maximum DC reverse voltage	V _R	60	V	
Maximum working peak reverse voltage	V _{RWM}	80	v	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS	
Maximum average forward current See fig. 5	$I_{F(AV)}$ 50 % duty cycle at T _C = 133 °C, rectangular waveform		, rectangular waveform	3.5		
Maximum peak one cycle non-repetitive surge current	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	490	А	
See fig. 7		'FSM	'FSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	70
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1 A, L = 12 mH		6.0	mJ	
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1.0	А	

* Pb containing terminations are not RoHS compliant, exemptions may apply





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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop See fig. 1	V _{FM} ⁽¹⁾	3 A	T _J = 25 °C	0.61	V
		6 A		0.76	
		3 A	T _J = 125 °C	0.53	
		6 A		0.65	
Maximum reverse leakage current See fig. 2	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	2	mA
	IRM (''	T _J = 125 °C		30	
Threshold voltage	V _{F(TO)}	$T_{\rm J} = T_{\rm J} \text{ maximum} \qquad \qquad$		0.38	V
Forward slope resistance	r _t			34.31	mΩ
Typical junction capacitance	CT	V_R = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 °C		145	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R 10 000		V/µs	

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	4.7	°C/W
Approximate weight			0.3	g
		0.01	oz.	
Marking device		Case style D-PAK (similar to TO-252AA)	30WQ	06FN

Note

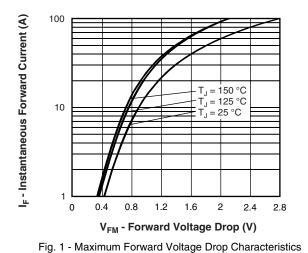
(1) $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$ thermal runaway condition for a diode on its own heatsink





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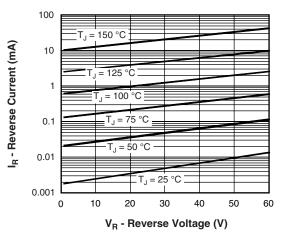


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

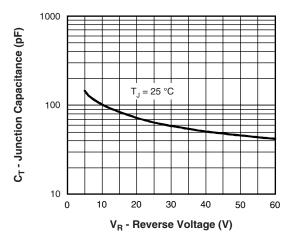


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

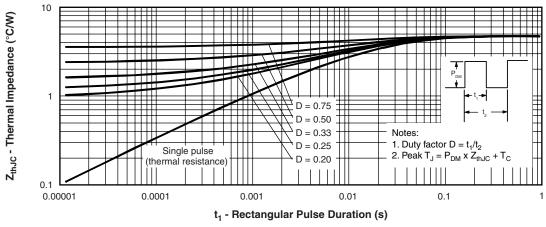


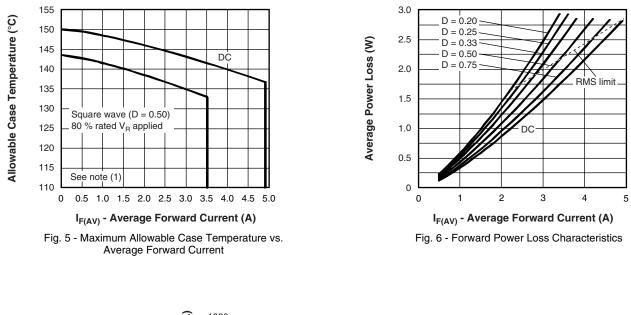
Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics

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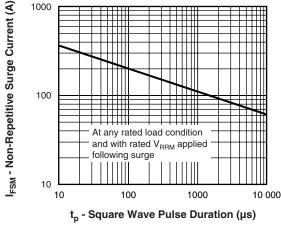


Fig. 7 - Maximum Non-Repetitive Surge Current

Note

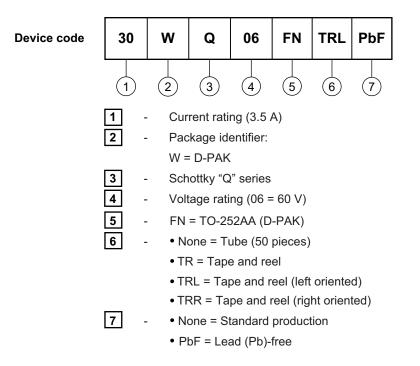
- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$; $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



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ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS			
Dimensions http://www.vishay.com/doc?95016			
Part marking information	http://www.vishay.com/doc?95059		
Packaging information	http://www.vishay.com/doc?95033		



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